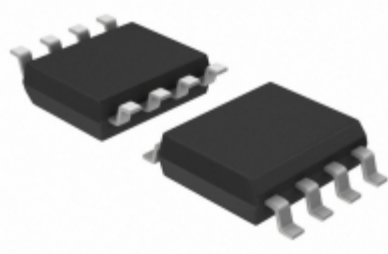


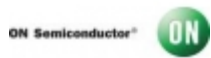


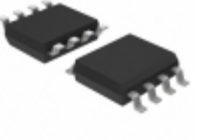
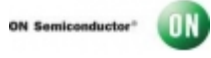
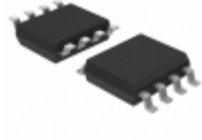
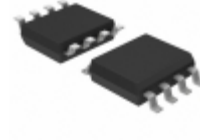
	<h2 style="color: #E67E22;">NTMSD6N303R2G</h2>	
	Hersteller-Teilenummer:	NTMSD6N303R2G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 30V 6A 8-SOIC
Datenblätter:	 NTMSD6N303R2G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 3565 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	NTMSD6N303R2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 6A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3565 pcs Stock
Serie	FETKY™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	2W (Ta)
Typ FET	N-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6A (Ta)
Rds On (Max) @ Id, Vgs	32 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	950pF @ 24V
Verpackung	Tape & Reel (TR)

NTMSD6N303R2G ist neu im Original, Suche NTMSD6N303R2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMSD6N303R2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMSD6N303R2G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMSD3P303R2 ON NTMSD3P303R2 ON</p>	 <p>NTMSD2P10LR2G AMI Semiconductor / ON Semiconductor NTMSD2P10LR2G ON</p>	 <p>NTMSD6N303R2 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p>	 <p>NTMSD3P303R2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 2.34A 8-SOIC</p>
 <p>NTMSD3P102R2 AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p>	 <p>NTMSD3P303DR2G AMI Semiconductor / ON Semiconductor NTMSD3P303DR2G ON</p>	 <p>NTMSD3P102R2SG AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p>	 <p>NTMSD6N303R2SG AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p>

heiße Teile

Mehr

NTMS4503NR2G	NTMS4700NR	NTMS4700NR2G	NTMS4704NR2G	NTMS4705NR2G
NTMS4706NR2G	NTMS4800NR2G	NTMS4801N	NTMS4801NR2G	NTMS4802N
NTMS4802NR2G	NTMS4807N	NTMS4807NR2G	NTMS4816N	NTMS4816NG
NTMS4816NR2G	NTMS4840NR2G	NTMS4872NR2G	NTMS4873NFR2G	NTMS4916AS001
NTMS4916N	NTMS4916NR2G	NTMS4916UT001	NTMS4917NR2G	NTMS4917UT001
NTMS4920N	NTMS4920NR2G	NTMS4937N	NTMS4937NR2G	NTMS4939N
NTMS4939NR2G	NTMS4N01R2	NTMS4P01R2G	NTMS5835NL	NTMS5835NLR2G
NTMS5838NLR2G	NTMS5P02	NTMS5P02R2	NTMS5P02R2G	NTMS7N03R2
NTMS7N03R2G	NTMS7N03R2R2G	NTMSD2P102LR2	NTMSD2P102R2	NTMSD3P102R2
NTMSD3P102R2SG	NTMSD3P303R2	NTMSD6N03R2G	NTMSD6N303R2	NTMSD6N303R2SG

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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